











MAX3243

SLLS3500 - APRIL 1999-REVISED JANUARY 2015

MAX3243 3-V to 5.5-V Multichannel RS-232 Line Driver/Receiver With ±15-kV ESD (HBM) **Protection**

Features

- Operates With 3-V to 5.5-V V_{CC} Supply
- Single-Chip and Single-Supply Interface for IBM™ PC/AT™ Serial Port
- RS-232 Bus-Pin ESD Protection of ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU V.28 Standards
- Three Drivers and Five Receivers
- Operates Up To 250 kbit/s
- Low Active Current: 300 µA Typical
- Low Standby Current: 1 µA Typical
- External Capacitors: 4 x 0.1 µF
- Accepts 5-V Logic Input With 3.3-V Supply
- Always-Active Noninverting Receiver Output (ROUT2B)
- **Operating Temperature**
 - MAX3243C: 0°C to 70°C
 - MAX3243I: –40°C to 85°C
- Serial-Mouse Driveability
- Auto-Powerdown Feature to Disable Driver Outputs When No Valid RS-232 Signal Is Sensed

2 Applications

- **Battery-Powered Systems**
- **Tablets**
- **Notebooks**
- Laptops
- Hand-Held Equipment

3 Description

The MAX3243 device consists of three line drivers, five line receivers which is ideal for DE-9 DTE interface. ±15-kV ESD (HBM) protection pin to pin (serial-port connection pins, including GND). Flexible power features saves power automatically. Special outputs ROUT2B and INVALID are always enabled to allow checking for ring indicator and valid RS232 input.

Device Information⁽¹⁾

PART NUMBER	PACKAGE (PIN)	BODY SIZE
	SSOP (28)	10.29 mm × 5.30 mm
MAX3243	SOIC (28)	17.90 mm × 7.50 mm
	TSSOP (28)	9.70 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Diagram

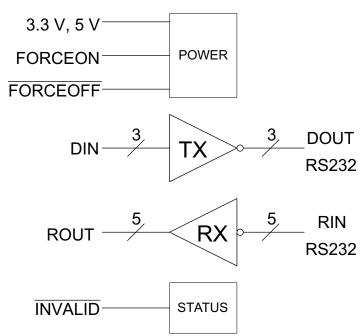




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5 Revision History

Changes from Revision N (May 2009) to Revision O

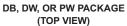
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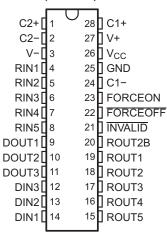
Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.

Deleted Ordering Information table.



6 Pin Configuration and Functions





Pin Functions

PIN		TYPE	DESCRIPTION		
NAME	NO.	ITPE	DESCRIPTION		
C2+	1	_	Positive lead of C2 capacitor		
C2-	2	_	Negative lead of C2 capacitor		
V–	3	0	Negative charge pump output for storage capacitor only		
RIN1:RIN5	4, 5, 6, 7, 8	ı	RS232 line data input (from remote RS232 system)		
DOUT1:DOUT3	9, 10, 11	0	RS232 line data output (to remote RS232 system)		
DIN3:DIN1	12, 13, 14	1	Logic data input (from UART)		
ROUT5:ROUT1	15, 16, 17, 18, 19	0	Logic data output (to UART)		
ROUT2B	20	0	Always Active non-inverting output for RIN2 (normally used for ring indicator)		
INVALID	21	0	Active low output when all RIN are unpowered		
FORCEOFF	22	1	Low input forces DOUT1-5, ROUT1-5 high Z per Device Functional Modes		
FORCEON	23	1	High forces drivers on. Low is automatic mode per <i>Device Functional Modes</i>		
C1-	24	_	Negative lead on C1 capacitor		
GND	25	_	Ground		
V _{CC}	26	_	Supply Voltage, Connect to 3V to 5.5V power supply		
V+	27	0	Positive charge pump output for storage capacitor only		
C1+	28	_	Positive lead of C1 capacitor		



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive output supply voltage range (2)		-0.3	7	V
V-	egative output supply voltage range ⁽²⁾		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
.,	land valtage reserve	Driver, FORCEOFF, FORCEON	-0.3	6	
V_{I}	Input voltage range	Receiver	-25	25	V
.,	Outrot valtage as as	Driver	-13.2	13 6 25 13.2 V _{CC} + 0.3	V
Vo	Output voltage range	Receiver, INVALID	-0.3	V _{CC} + 0.3	V
TJ	Operating virtual junction temperature	·		150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			MAX	UNIT
V _(ESD)		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 RIN , DOUT, and GND pins $^{(1)}$	15000	
	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 All other pins ⁽¹⁾	3000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	1000	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

(1)(See Figure 8)

				MIN	NOM	MAX	UNIT
\/			V _{CC} = 3.3 V	3	3.3	3.6	V
vcc	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	V
\/	7 _{IH} Driver and control high-level input voltage	DIN, FORCEOFF,	$V_{CC} = 3.3 \text{ V}$	2		5.5	V
VIH		FORCEON	$V_{CC} = 5 V$	2.4		5.5	V
V_{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCE	CEON	0		0.8	V
V_{I}	Driver and control input voltage	DIN, FORCEOFF, FORCE	CEON	0		5.5	V
V_{I}	Receiver input voltage			-25		25	V
т	Operating free cir temperature		MAX3243C	0		70	°C
T _A	Operating free-air temperature		MAX3243I	-40		85	C

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

7.4 Thermal Information

			MAX3243		
THERMAL METRIC ⁽¹⁾		DB	DW	PW	UNIT
		16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	62	46	62	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

⁽²⁾ All voltages are with respect to network GND.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics — Auto Power Down

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1) (see Figure 8)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
	Supply current Auto-powerdown disabled	No load, $\overline{\text{FORCEOFF}}$ and $\overline{\text{FORCEON}}$ at V_{CC} . $T_A = 25^{\circ}\text{C}$		0.3	1	mA
I _{CC}	Supply current Powered off	No load, $\overline{\text{FORCEOFF}}$ at GND. $T_A = 25^{\circ}\text{C}$		1	10	
	Supply current Auto-powerdown enabled	No load, $\overline{FORCEOFF}$ at V_{CC} , FORCEON at GND, All RIN are open or grounded, All DIN are grounded. $T_A = 25^{\circ}C$		1	10	μΑ
I	Input leakage current of FORCEOFF, FORCEON	$V_I = V_{CC}$ or V_I at GND		±0.01	±1	μΑ
V _{IT+}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}			2.7	V
V _{IT-}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-2.7			V
V _T	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-0.3		0.3	V
V _{OH}	INVALID high-level output voltage	I _{OH} = -1 mA, FORCEON = GND, FORCEOFF = V _{CC}	V _{CC} - 0.6			V
V _{OL}	INVALID low-level output voltage	I_{OL} = 1.6 mA, FORCEON = GND, FORCEOFF = V_{CC}			0.4	V

7.6 Electrical Characteristics — Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1) (see Figure 8)

	PARAMETER	TES	ST CONDITIONS		MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to Ω	GND		5	5.4		V
V _{OL}	Low-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to Ω	GND		-5	-5.4		V
Vo	Output voltage (mouse driveability)		DIN1 = DIN2 = GND, DIN3 = V_{CC} , 3-kΩ to GND at DOUT3, DOUT1 = DOUT2 = 2.5 mA		±5			V
I _{IH}	High-level input current	$V_I = V_{CC}$				±0.01	±1	μΑ
I _{IL}	Low-level input current	V _I at GND				±0.01	±1	μΑ
V_{hys}	Input hysteresis						±1	V
	Chart aircuit autaut aurrant (3)	V _{CC} = 3.6 V,	V _O = 0 V			.25	.60	A
Ios	Short-circuit output current (3)	$V_{CC} = 5.5 \text{ V},$	$V_O = 0 V$			±35	±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V		300	10M		Ω
	Output lookage augrent	FORCEOFF = GND,	V _O = ±12 V,	V _{CC} = 3 to 3.6 V			±25	
I _{off}	Output leakage current	FURGEOFF = GND,	V _O = ±10 V,	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$			±25	μΑ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.



7.7 Electrical Characteristics — Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1) (see Figure 8)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.6	V _{CC} – 0.1		V
V_{OL}	Low-level output voltage	I _{OH} = 1.6 mA			0.4	V
V	Desitive going input threshold voltage	V _{CC} = 3.3 V		1.6	2.4	V
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		1.9	2.4	V
V	Negative going input threehold voltage	V _{CC} = 3.3 V	0.6	1.1		٧
V _{IT} -	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.4		V
V_{hys}	Input hysteresis (V _{IT+} – V _{IT-})			0.5		V
I _{off}	Output leakage current (except ROUT2B)	FORCEOFF = 0 V		±0.05	±10	μΑ
rı	Input resistance	$V_I = \pm 3 \text{ V or } \pm 25 \text{ V}$	3	5	7	kΩ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

7.8 Switching Characteristics — Auto Power Down

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 7)

	PARAMETER	TEST CONDITIONS	TYP ⁽¹⁾	UNIT
t _{valid}	Propagation delay time, low- to high-level output	$V_{CC} = 5 V$	1	μs
t _{invali}	Propagation delay time, high- to low-level output	$V_{CC} = 5 V$	30	μs
t _{en}	Supply enable time	$V_{CC} = 5 V$	100	μs

⁽¹⁾ All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25 ^{\circ}\text{C}$.

7.9 Switching Characteristics — Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1) (see Figure 8) MAX3243C, MAX3243I

	PARAMETER	TEST CONDITIONS		MIN	TYP ⁽²⁾ MAX	UNIT	
	Maximum data rate	$R_L = 3 \text{ k}\Omega$ One DOUT switching,	C _L = 1000 pF See Figure 3	150	250	kbit/s	
t _{sk(p)}	Pulse skew ⁽³⁾	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega$	C _L = 150 pF to 2500 pF See Figure 5		100	ns	
CD/+=\	Slew rate, transition region (see Figure 3)	Slew rate, transition region $V_{CC} = 3.3 \text{ V}$.	$V_{CC} = 3.3 \text{ V},$	C _L = 150 pF to 1000 pF	6	30	1////
SR(tr)		$R_L = 3 k\Omega$ to $7 k\Omega$	C _L = 150 pF to 2500 pF	4	30	V/µs	

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V + 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

7.10 Switching Characteristics — Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	TYP ⁽²⁾	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF,	150	ns
t _{PHL}	Propagation delay time, high- to low-level output	See Figure 5	150	ns
t _{en}	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega,$	200	ns
t _{dis}	Output disable time	See Figure 6	200	ns
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 5	50	ns

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25 ^{\circ}\text{C}$.

Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

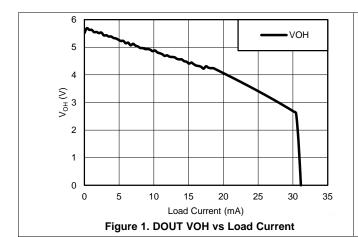
All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Pulse skew is defined as $|t_{\text{PLH}}$ - $t_{\text{PHL}}|$ of each channel of the same device.



7.11 Typical Characteristics

 $V_{CC} = 3.3 \text{ V}$



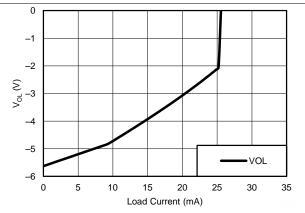
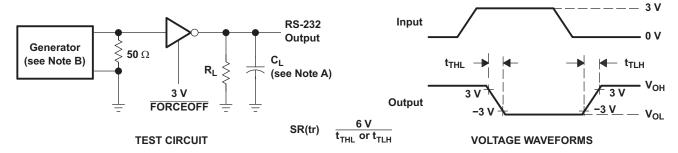


Figure 2. DOUT VOL vs Load Current

TEXAS INSTRUMENTS

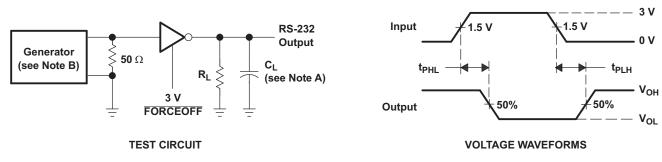
8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s (MAX3243C/I) and 1 Mbit/s (MAX3243FC/I), $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns.

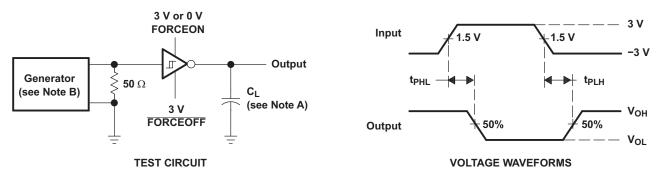
Figure 3. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s (MAX3243C/I) and 1 Mbit/s (MAX3243FC/I), $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns.

Figure 4. Driver Pulse Skew



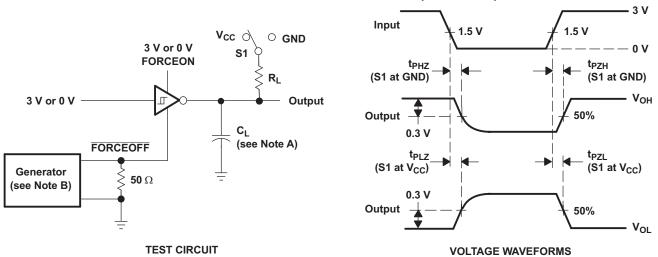
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns.

Figure 5. Receiver Propagation Delay Times



Parameter Measurement Information (continued)



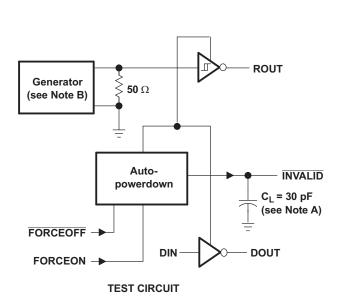
NOTES: A. C_L includes probe and jig capacitance.

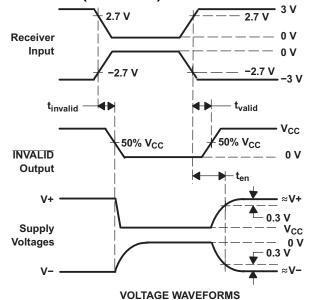
- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- D. t_{PZL} and t_{PZH} are the same as t_{en}.

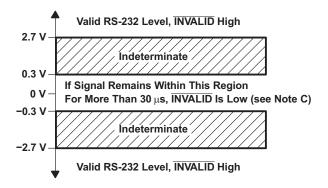
Figure 6. Receiver Enable and Disable Times



Parameter Measurement Information (continued)







NOTES: A. C_L includes probe and jig capacitance.

- B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
- C. Auto-powerdown disables drivers and reduces supply current to $1\,\mu\text{A}.$

Figure 7. INVALID Propagation Delay Times and Supply Enabling Time

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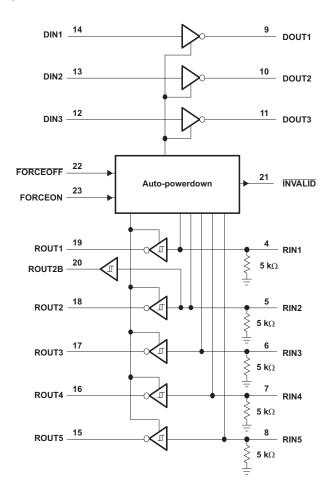


9 Detailed Description

9.1 Overview

The MAX3243 device consists of three line drivers, five line receivers, and a dual charge-pump circuit with ±15kV ESD (HBM) protection pin to pin (serial- port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. This combination of drivers and receivers matches that needed for the typical serial port used in an IBM PC/AT, or compatible. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, the device includes an always-active noninverting output (ROUT2B), which allows applications using the ring indicator to transmit data while the device is powered down. Flexible control options for power management are available, when the serial port is inactive. The autopower-down feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low, both drivers and receivers (except ROUT2B) are shut off, and the supply current is reduced to 1 µA. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Autopowerdown can be disabled when FORCEON and FORCEOFF are high and should be done when driving a serial mouse. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than 30 µs. INVALID is low (invalid data) if all receiver input voltages are between -0.3 V and 0.3 V for more than 30 µs.

9.2 Functional Block Diagram





9.3 Feature Description

9.3.1 Auto-Power-Down

Auto-Power-Down can be used to automatically save power when the receivers are unconnected or connected to a powered down remote RS232 port. FORCEON being high will override Auto power down and the drivers will be active. FORCEOFF being low will override FORCEON and will power down all outputs except for ROUT2B and INVALID.

9.3.2 Charge Pump

The charge pump increases, inverts, and regulates voltage at V+ and V- pins and requires four external capacitors.

9.3.3 RS232 Driver

Three drivers interface standard logic level to RS232 levels. All DIN inputs must be valid high or low.

9.3.4 RS232 Receiver

Five receivers interface RS232 levels to standard logic levels. An open input will result in a high output on ROUT. Each RIN input includes an internal standard RS232 load.

9.3.5 ROUT2B Receiver

ROUT2B is an always-active noninverting output of RIN2 input, which allows applications using the ring indicator to transmit data while the device is powered down.

9.3.6 Invalid Input Detection

The INVALID output goes active low when all RIN inputs are unpowered. The INVALID output goes inactive high when any RIN input is connected to an active RS232 voltage level.

Product Folder Links: MAX3243

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9.4 Device Functional Modes

Table 1. Each Driver⁽¹⁾

	INP	UTS	OUTPUT		
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
X	Χ	L	Χ	Z	Powered off
L	Н	Н	X	Н	Normal operation with
Н	Н	Н	X	L	auto-powerdown disabled
L	L	Н	YES	Н	Normal operation with
Н	L	Н	YES	L	auto-powerdown enabled
X	L	Н	NO	Z	Power off by auto-powerdown feature

(1) H = high level, L = low level, X = irrelevant, Z = high impedance, YES = any RIN valid, NO = all RIN invalid

Table 2. Each Receiver (1)

	INPUTS		OUTPUTS	RECEIVER STATUS
RIN	FORCEON	FORCEOFF	ROUT	RECEIVER STATUS
Х	Х	L	Z	Powered off
L	Х	Н	Н	
Н	Х	Н	L	Normal operation
Open	Х	Н	Н	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

Table 3. INVALID and ROUT2B Outputs(1)

	INP	PUTS		OUT	PUTS	
VALID RIN RS-232 LEVEL	RIN2	FORCEON	FORCEOFF	INVALID	ROUT2B	OUTPUT STATUS
YES	L	Х	Х	Н	L	Alwaya Active
YES	Н	X	X	Н	Н	Always Active
YES	OPEN	Х	X	Н	L	Alwaya Active
NO	OPEN	Х	Х	L	L	Always Active

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), OPEN = input disconnected or connected driver off, YES = any RIN valid, NO = all RIN invalid



10 Application and Implementation

NOTE

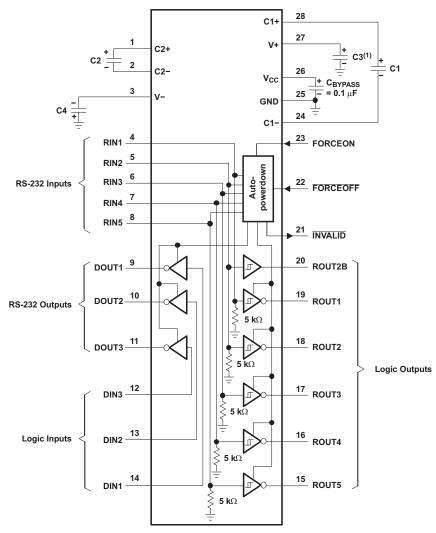
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

It is recommended to add capacitors as shown in Figure 8.

10.2 Typical Application

ROUT and DIN connect to UART or general purpose logic lines. RIN and DOUT lines connect to a RS232 connector or cable.



(1) C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown. V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
$3.3~\text{V}\pm0.3~\text{V}$ $5~\text{V}\pm0.5~\text{V}$ $3~\text{V}$ to $5.5~\text{V}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF

Figure 8. Typical Operating Circuit and Capacitor Values

Submit Documentation Feedback



Typical Application (continued)

10.2.1 Design Requirements

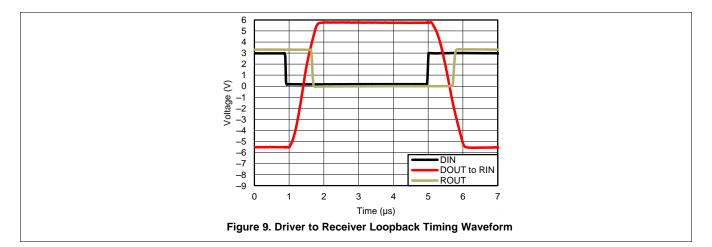
- V_{CC} minimum is 3 V and maximum is 5.5V.
- · Maximum recommended bit rate is 250 kbit/s.

10.2.2 Detailed Design Procedure

- All DIN, FORCEOFF and FORCEON inputs must be connected to valid low or high logic levels.
- Select capacitor values based on V_{CC} level for best performance.

10.2.3 Application Curves

 V_{CC} = 3.3 V





11 Power Supply Recommendations

V_{CC} should be between 3 V and 5.5 V. Charge pump capacitors should be chosen using table in Figure 8.

12 Layout

12.1 Layout Guidelines

Keep the external capacitor traces short. This is more important on C1 and C2 nodes that have the fastest rise and fall times.

In the *Layout Example* diagram, only critical layout sections are shown. Input and output traces will vary in shape and size depending on the customer application. FORCEON and /FORCEOFF should be pulled up to VCC or GND via a pullup resistor, depending on which configuration the user desires upon power-up.



12.2 Layout Example

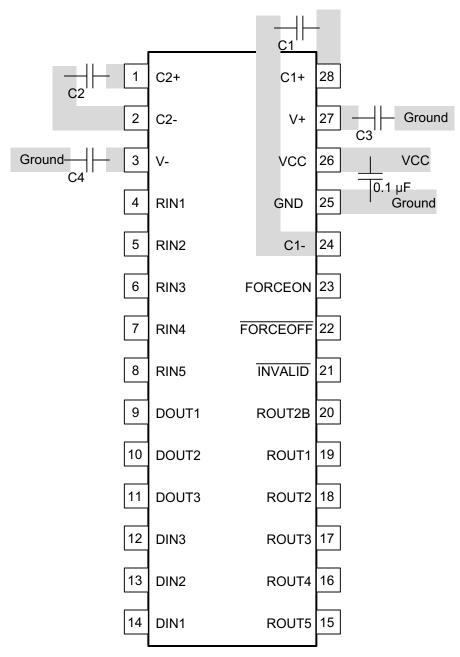


Figure 10. Layout Diagram



13 Device and Documentation Support

13.1 Trademarks

IBM, PC/AT are trademarks of IBM.

All other trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3243CDB	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDBG4	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDBRE4	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDBRG4	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDW	ACTIVE	SOIC	DW	28	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDWE4	ACTIVE	SOIC	DW	28	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CDWRG4	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3243C	Samples
MAX3243CPW	ACTIVE	TSSOP	PW	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3243C	Samples
MAX3243CPWE4	ACTIVE	TSSOP	PW	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3243C	Samples
MAX3243CPWR	ACTIVE	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3243C	Samples
MAX3243CPWRG4	ACTIVE	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3243C	Samples
MAX3243IDB	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDBG4	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDW	ACTIVE	SOIC	DW	28	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDWRE4	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples
MAX3243IDWRG4	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3243I	Samples



PACKAGE OPTION ADDENDUM

10-Dec-2020

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3243IPW	ACTIVE	TSSOP	PW	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3243I	Samples
MAX3243IPWR	ACTIVE	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3243I	Samples
MAX3243IPWRE4	ACTIVE	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3243I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF MAX3243:

■ Enhanced Product: MAX3243-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3243CDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3243CDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3243CPWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MAX3243IDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3243IDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3243IDWRG4	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3243IPWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3243CDBR	SSOP	DB	28	2000	853.0	449.0	35.0
MAX3243CDWR	SOIC	DW	28	1000	350.0	350.0	66.0
MAX3243CPWR	TSSOP	PW	28	2000	853.0	449.0	35.0
MAX3243IDBR	SSOP	DB	28	2000	853.0	449.0	35.0
MAX3243IDWR	SOIC	DW	28	1000	350.0	350.0	66.0
MAX3243IDWRG4	SOIC	DW	28	1000	350.0	350.0	66.0
MAX3243IPWR	TSSOP	PW	28	2000	853.0	449.0	35.0

DW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AE.



DW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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